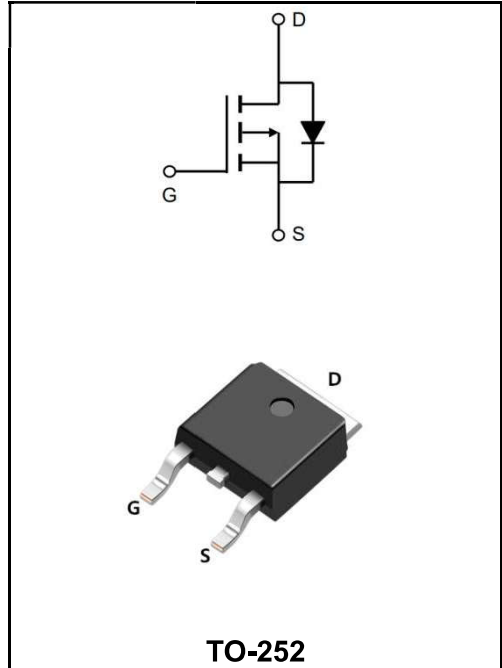


-40V P-CHANNEL ENHANCEMENT MODE MOSFET

MAIN CHARACTERISTICS

I_D	-10A
V_{DSS}	-40V
R_{DS(on)-typ(@V_{GS}=-10V)}	< 65mΩ (Type:60 mΩ)



Application

- ◆ Battery protection
- ◆ Load switch
- ◆ Uninterruptible power supply

Product Specification Classification

Part Number	Package	Marking	Pack
YFW10P04AD	TO-252	YFW 10P04AD XXXXX	2500PCS/Tape

Maximum Ratings at T_c=25°C unless otherwise specified

Characteristics	Symbols	Value	Units
Drain-Source Voltage	V_{DS}	-40	V
Gate - Source Voltage	V_{GS}	±20	V
Continuous Drain Current, V _{GS} @ -10V ¹ @T _C =25°C	I_D	-10	A
Continuous Drain Current, V _{GS} @ -10V ¹ @T _C =100°C	I_D	-7	A
Continuous Drain Current, V _{GS} @ -10V ¹ @T _A =25°C	I_D	-4.5	A
Continuous Drain Current, V _{GS} @ -10V ¹ @T _A =70°C	I_D	-3.6	A
Pulsed Drain Current ²	I_{DM}	-32	A
Single Pulse Avalanche Energy ³	E_{AS}	21	mJ
Avalanche Current	I_{AS}	-20.5	A
Total Power Dissipation ⁴ @T _C =25°C	P_D	25	W
Total Power Dissipation ⁴ @T _A =25°C	P_D	2	W
Storage Temperature Range	T_{STG}	-55 to +150	°C
Operating Junction Temperature Range	T_J	-55 to +150	°C
Thermal Resistance Junction-Ambient ¹	R_{θJA}	62	°C/W
Thermal Resistance Junction to Case ¹	R_{θJC}	5	°C/W

Maximum Ratings at Tc=25°C unless otherwise specified

Characteristics	Test Condition	Symbols	Min	Typ	Max	Units
Drain-Source Breakdown Voltage	$V_{GS}=0V, I_D=-250\mu A$	BV_{DSS}	-40	-47	-	V
BV_{DSS} Temperature Coefficient	Reference to 25°C, $I_D=-1mA$	$\Delta BV_{DSS}/\Delta T_J$	-	-0.015	-	V/°C
Static Drain-Source On-Resistance ²	$V_{GS}=-10V, I_D=-8A$	$R_{DS(ON)}$	-	60	65	mΩ
	$V_{GS}=-4.5V, I_D=-4A$		-	85	100	
Gate -Threshold Voltage	$V_{DS}=V_{GS}, I_D=-250\mu A$	$V_{GS(th)}$	-1.0	-1.6	-2.5	V
$V_{GS(th)}$ Temperature Coefficient		$\Delta V_{GS(th)}$	-	3.52	-	mV/°C
Drain-Source Leakage Current	$V_{DS}=-32V, V_{GS}=0V, T_J=25^\circ C$	I_{DSS}	-	-	1	μA
	$V_{DS}=-32V, V_{GS}=0V, T_J=55^\circ C$		-	-	5	
Gate -Source Leakage Current	$V_{GS}=\pm 20V, V_{DS}=0V$	I_{GSS}	-	-	±100	nA
Forward Transconductance	$V_{DS}=-10V, I_D=-10A$	g_{fs}	-	6	-	S
Total Gate Charge(-4.5V)	$V_{DS}=-20V$ $V_{GS}=-4.5V$ $I_D=-8A$	Q_g	-	5.8	-	nC
Gate-Source Charge		Q_{gs}	-	1.2	-	
Gate-Drain Charge		Q_{gd}	-	2.1	-	
Turn-on delay time	$V_{DD}=-15V$ $V_{GS}=-10V$ $I_D=-1A$ $R_G=3.3\Omega$	$t_{d(on)}$	-	13.2	-	ns
Rise Time		T_r	-	8	-	
Turn-Off Delay Time		$t_{d(OFF)}$	-	40	-	
Fall Time		t_f	-	3.5	-	
Input Capacitance	$V_{DS}=-15V$ $V_{GS}=0V$ $f=1MHz$	C_{iss}	-	620	-	pF
Output Capacitance		C_{oss}	-	69	-	
Reverse Transfer Capacitance		C_{rss}	-	52	-	
Continuous Source Current ^{1,5}	$V_G=V_D=0V, \text{Force Current}$	I_S	-	-	-16	A
Pulsed Source Current ^{2,5}		I_{SM}	-	-	-32	A
Diode Forward Voltage ²	$V_{GS}=0V, I_S=-1A, T_J=25^\circ C$	V_{SD}	-	-	-1.2	V

Note :

- 1、 The data tested by surface mounted on a 1 inch 2 FR-4 board with 2OZ copper.
- 2、 The data tested by pulsed , pulse width $\leq 300\mu s$, duty cycle $\leq 2\%$
- 3、 The EAS data shows Max. rating . The test condition is $V_{DD}=-25V, V_{GS}=-10V, L=0.1mH, I_{AS}=-20.5A$
- 4、 The power dissipation is limited by 150°C junction temperature
- 5、 The data is theoretically the same as I_D and I_{DM} , in real applications , should be limited by total power dissipation

Ratings and Characteristic Curves

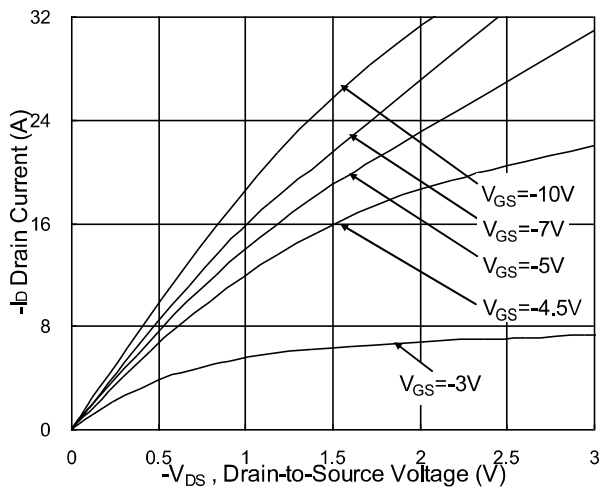


Fig.1 Typical Output Characteristics

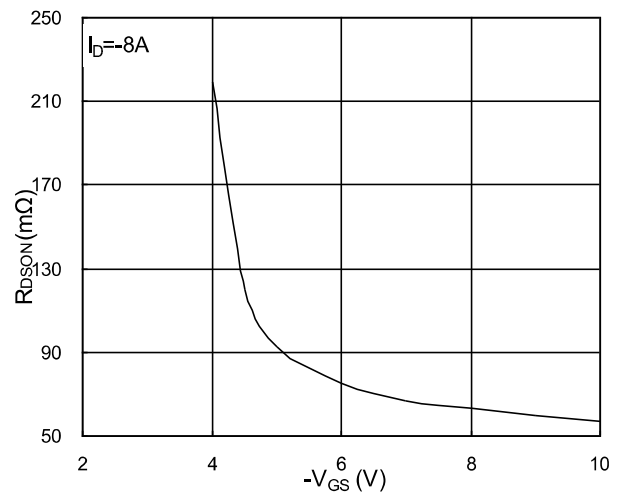


Fig.2 On-Resistance v.s Gate-Source

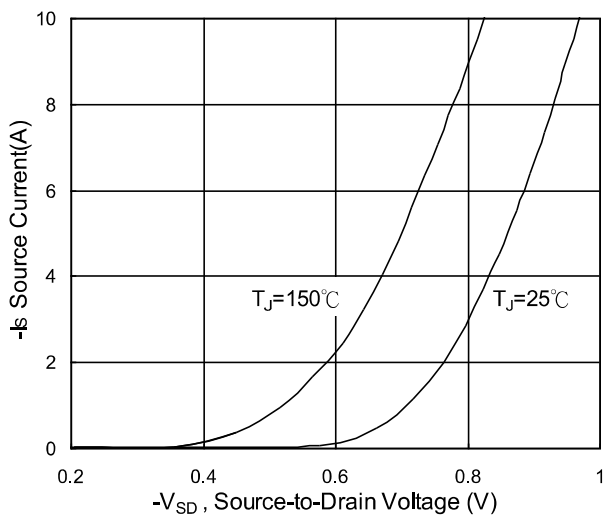


Fig.3 Forward Characteristics Of Reverse

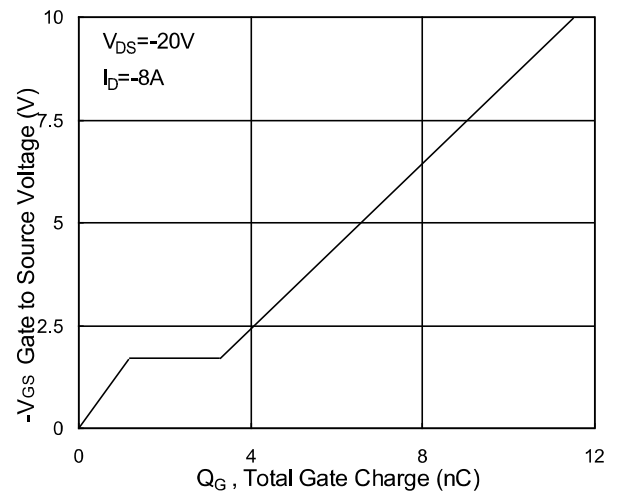


Fig.4 Gate Charge Characteristics

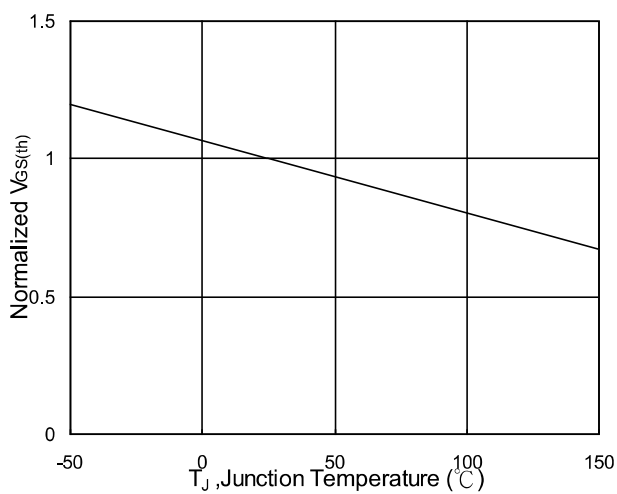


Fig.5 Normalized $V_{GS(th)}$ v.s T_J

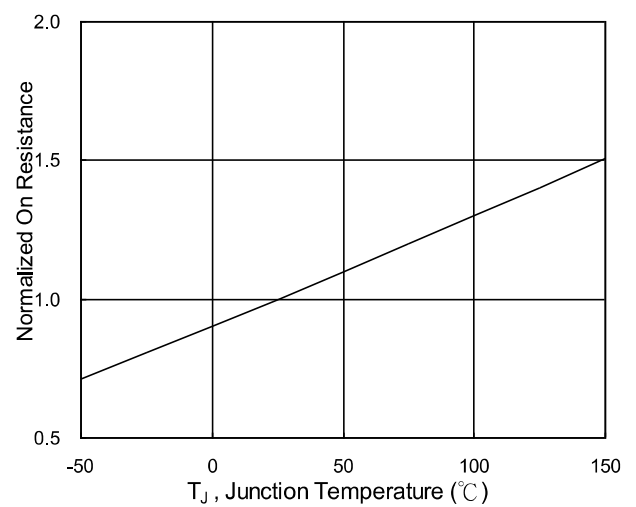


Fig.6 Normalized $R_{DS(on)}$ v.s T_J

Ratings and Characteristic Curves

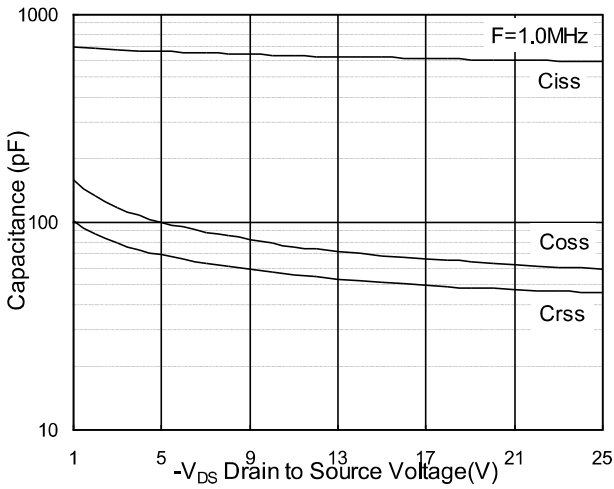


Fig.7 Capacitance

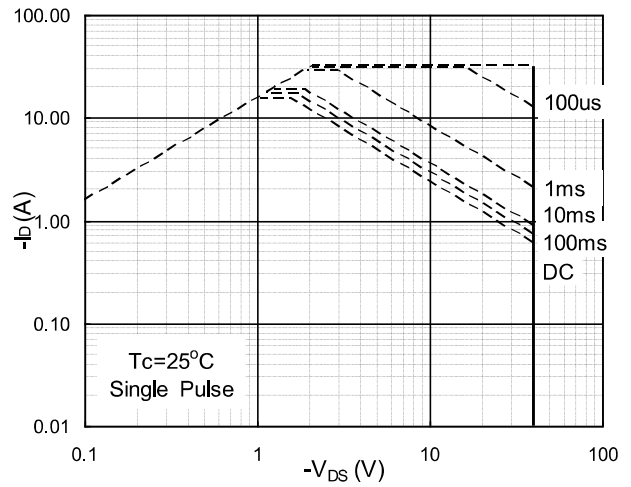


Fig.8 Safe Operating Area

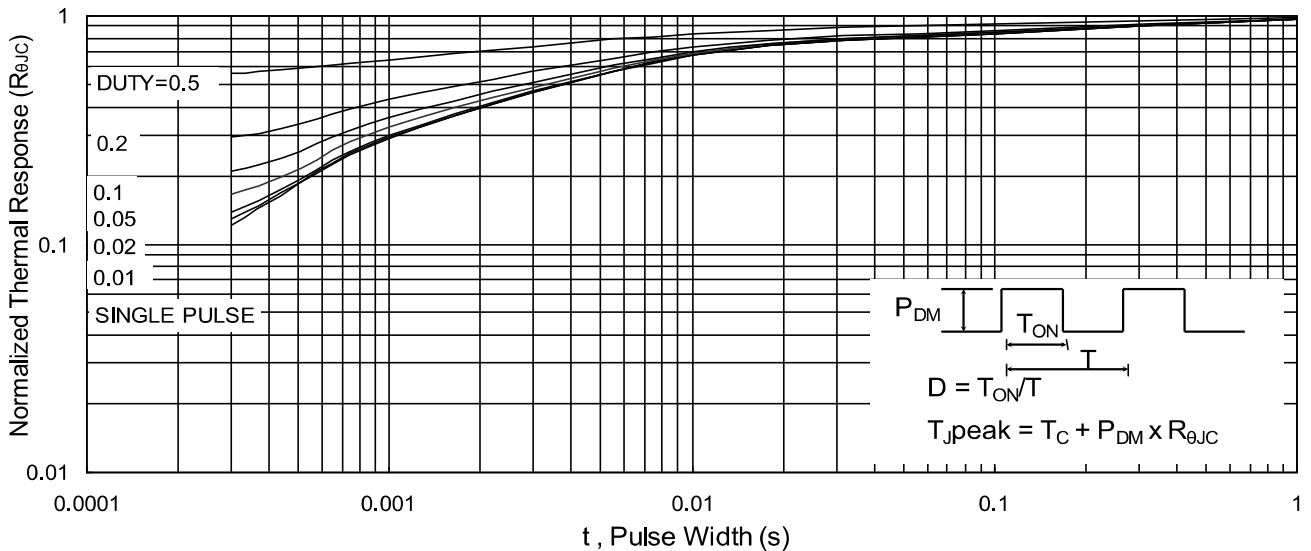


Fig.9 Normalized Maximum Transient Thermal Impedance

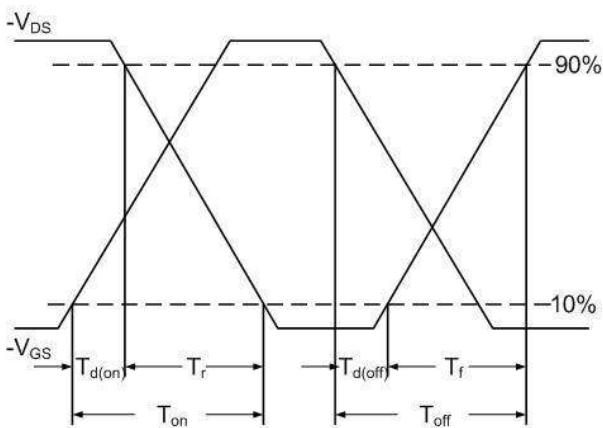


Fig.10 Switching Time Waveform

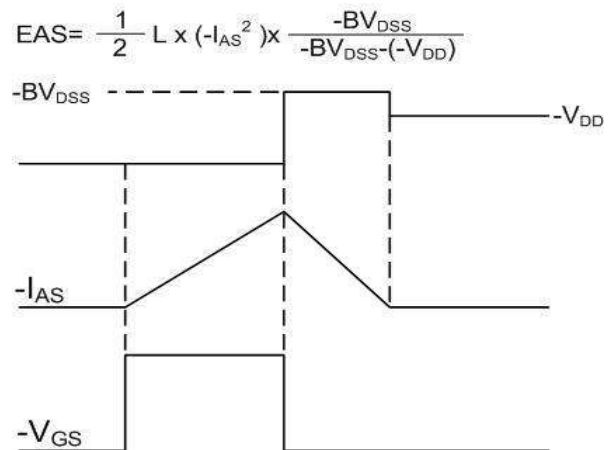


Fig.11 Unclamped Inductive Switching Waveform

Package Outline Dimensions Millimeters

TO-252

Dim.	Min.	Typ.	Max.
A	2.10	-	2.50
A2	0	-	0.10
B	0.66	-	0.86
B2	5.18	-	5.48
C	0.40	-	0.60
C2	0.44	-	0.58
D	5.90	-	6.30
D1	5.30REF		
E	6.40	-	6.80
E1	4.63	-	-
G	4.47	-	4.67
H	9.50	-	10.70
L	1.09	-	1.21
L2	1.35	-	1.65
V1	-	7°	-
V2	0°	-	6°
All Dimensions in millimeter			

